

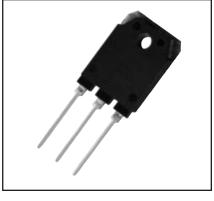
Triac 30 Ampere/400-600 Volts

OUTLINE DRAWING CONNECTION DIAGRAM ① T1 TERMINAL 2 T2 TERMINAL ③ GATE **4** T2 TERMINAL



Dimensions	Inches	Millimeters
А	0.79	20.0
В	0.77	19.5
С	0.63	15.9
D	0.20	5.0
E	0.16	4.0
F	0.08	2.0
G	0.13 Dia.	3.2 Dia.
Н	0.08	2.0

Dimensions	Inches	Millimeters
J	0.04	1.0
K	0.21	5.45
L	0.18	4.5
М	0.06	1.5
N	0.02	0.6
Р	0.17	4.4
Q	0.11	2.8
R	0.16	4.0



Description:

A triac is a solid state silicon AC switch which may be gate triggered from an off-state to an on-state for either polarity of applied voltage.

Features:

- ☐ Planar Passivation
- □ Selected for Inductive Loads

Applications:

- ☐ Contactless AC Switches
- ☐ Microwave Ovens
- ☐ Lighting Controls

Ordering Information:

Example: Select the complete eight, nine or ten digit part number you desire from the table - i.e. BCR30AM-8 is a 400 Volt, 30 Ampere Triac.

Туре	V _{DRM} Volts	Code	Inductive Load*
BCR30AM	400 600	-8 -12	L

^{*}For inductive load, add L.



BCR30AM Triac

30 Ampere/400-600 Volts

Absolute Maximum Ratings, $T_a = 25$ °C unless otherwise specified

Ratings	Symbol	BCR30AM-8	BCR30AM-12	Units
On-state Current, T _C = 75°C	I _{T(RMS)}	30	30	Amperes
Repetitive Peak Off-state Voltage (Gate Open)	V _{DRM}	400	600	Volts
Non-repetitive Peak Off-state Voltage (Gate Open)	V _{DSM}	500	720	Volts
Non-repetitive Peak On-state Voltage, One Cycle (60 Hz	z) I _{TSM}	300	300	Amperes
I ² t for Fusing, t = 8.3 msec	I ² t	378	378	A ² sec
Peak Gate Power Dissipation, 20 μsec	P _{GM}	5	5	Watts
Average Gate Power Dissipation	P _{G(avg)}	0.5	0.5	Watts
Peak Gate Current	I _{GM}	2	2	Amperes
Peak Gate Voltage	V_{GM}	10	10	Volts
Storage Temperature	T _{stg}	-40 to 125	-40 to 125	°C
Operating Temperature	Tj	-40 to 125	-40 to 125	°C
Weight	_	4.8	4.8	Grams

Electrical and Thermal Characteristics, T_j = 25 °C unless otherwise specified

		Test Conditions (Trigger Mode)			BCR30GM				
Characteristics	Symbol	v_{D}	R_{L}	R_{G}	Τj	Min.	Typ.	Max.	Units
Gate Parameters DC Gate Trigger Current									
MT2+ Gate+	I _{FGT} I	6V	6Ω	330Ω	25°C	_	_	50	mA
MT2+ Gate-	I _{RGT} I	6V	6Ω	330Ω	25°C	_	_	50	mA
MT2- Gate-	I _{RGT} III	6V	6Ω	330Ω	25°C	_	_	50	mA
DC Gate Trigger Voltage									
MT2+ Gate+	V _{FGT} I	6V	6Ω	330Ω	25°C	_	_	2.5	Volts
MT2+ Gate-	V _{RGT} I	6V	6Ω	330Ω	25°C	-	-	2.5	Volts
MT2- Gate-	V _{RGT} III	6V	6Ω	330Ω	25°C	_	_	2.5	Volts
DC Gate Non-trigger Voltage									
All	V _{GD}	1/2 V _{DRM}	-	-	125°C	0.2	-	-	Volts

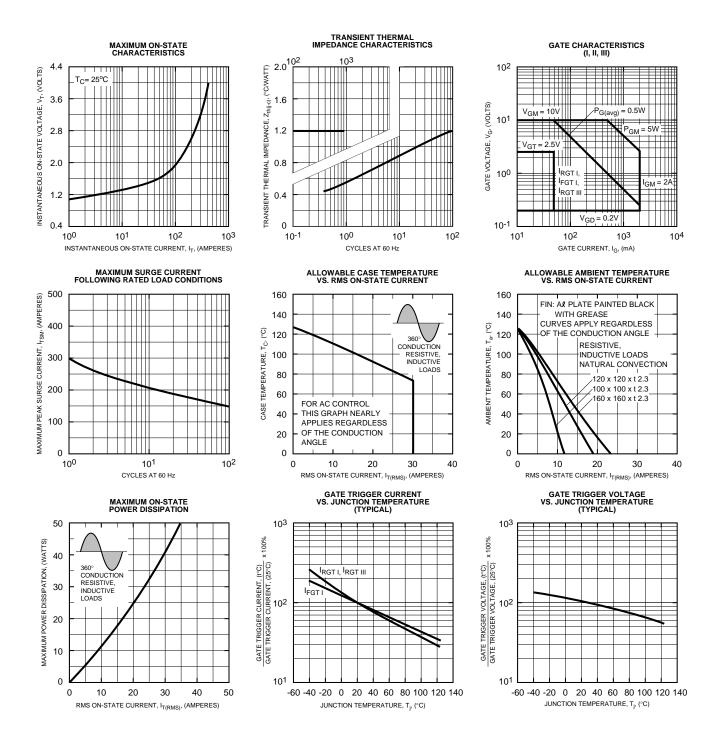
Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal Resistance, Junction-to-case	R _{th(c-f)}	-	-	_	1.2	°C/W
Voltage – Blocking State Repetitive Off-state Current	I _{DRM}	Gate Open Circuited, V _D = V _{DRM} , T _j = 125°C	-	-	3	mA
Current – Conducting State Peak On-state Voltage	V_{TM}	$T_C = 25^{\circ}C$, $I_{TM} = 45A$	_	-	1.6	Volts
Critical Rate-of-Rise of Commutating Off-state Voltage (Commutating dv/dt) • (Switching)	(dv/dt) _C	-	-	-	-	V/μs



BCR30AM

Triac

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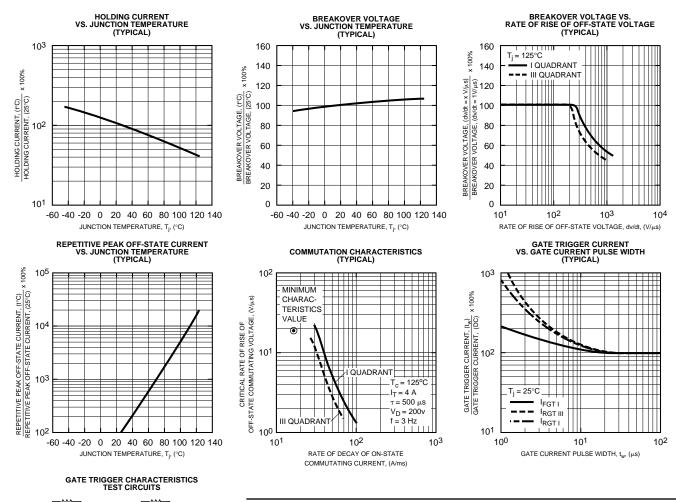




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$ \begin{array}{c c} \hline 60 \\ \hline 60 \\ \hline \end{array} $ $ \begin{array}{c c} \hline R_G \\ \hline \end{array} $ $ \begin{array}{c c} \hline \end{array} $	Δ Part Number	V _{DRM} (Volts)	Commutatir dv/dt, (dv/dt (V/µsec) Minimum	t) _c	Commutating Voltage & Current Waveform (Inductive Load)
	BCR30AM-8L	400	20	Tj = 125°C,	SUPPLY VOLTAGE
TEST PROCEDURE I TEST PROCEDURE II	BCR30AM-12L	600	20	Rate of Decay	(di/dt) _C
GΩ R _G				On-state Commutating Current (di/dt) _C = -016A/msec, Peak Off-state	MAIN CURRENT TVD
TEST PROCEDURE III				Voltage $V_D = 400V$	VOLTAGE (dv/dt) _C t

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Datasheets for electronics components.